NSR02530NXT5G

Schottky Barrier Diode

These Schottky barrier diodes are optimized for low forward voltage drop and low leakage current. The DSN2 (Dual Silicon No-lead) package is a chip level package using solderable metal contacts under the package similar to DFN style packages. The DSN style package enables 100% utilization of the package area for active silicon, offering a significant performance per board area advantage compared to products in plastic molded packages. The low thermal resistance enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

Features

- Very Low Forward Voltage Drop 370 mV @ 10 mA
- Low Reverse Current 7.0 μA @ 10 V VR
- 200 mA of Continuous Forward Current
- ESD Rating Human Body Model: Class 3B
 - Machine Model: Class C
- Very High Switching Speed
- Low Capacitance CT = 7 pF
- This is a Halide-Free Device
- This is a Pb-Free Device

Typical Applications

- LCD and Keypad Backlighting
- Camera Photo Flash
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

Markets

- Mobile Handsets
- MP3 Players
- Digital Camera and Camcorders
- Notebook PCs & PDAs
- GPS

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Reverse Voltage		V _R	30	V
Forward Current	IF	200	mA	
Forward Surge Current (60 Hz @ 1 cycle)		I _{FSM}	4.0	А
ESD Rating:	Human Body Model Machine Model	ESD	>8.0 >400	kV V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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30 V SCHOTTKY BARRIER DIODE





DSN2 (0201) CASE 152AA

MARKING DIAGRAM

PIN 1

V230 = Specific Device Code YYY = Year Code

ORDERING INFORMATION

Device	Package	Shipping†		
NSR02F30NXT5G	DSN2 (Pb-Free)	5000 / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NSR02F30NXT5G

ZHERMAN, ROHARA OTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
Thermal Resistance Junction-to-Ambient (Note 1) Total Power Dissipation @ T _A = 25°C	R _{θJA} P _D			400 312	°C/W mW
Thermal Resistance Junction-to-Ambient (Note 2) Total Power Dissipation @ T _A = 25°C	R _{θJA} P _D			170 735	°C/W mW
Storage Temperature Range	T _{stg}			-40 to +125	°C
Junction Temperature	TJ			+125	°C

Mounted onto a 4 in square FR-4 board 10 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.
 Mounted onto a 4 in square FR-4 board 1 in sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Leakage (V _R = 10 V) (V _R = 30 V)	I _R			7.0 50	μΑ
Forward Voltage (I _F = 10 mA) (I _F = 200 mA)	V _F			0.37 0.55	V
Total Capacitance (V _R = 5.0 V, f = 1 MHz)	СТ		7.0		pF

NSR02F30NXT5G

查询"NSR02F30-D"供应商

TYPICAL CHARACTERISTICS

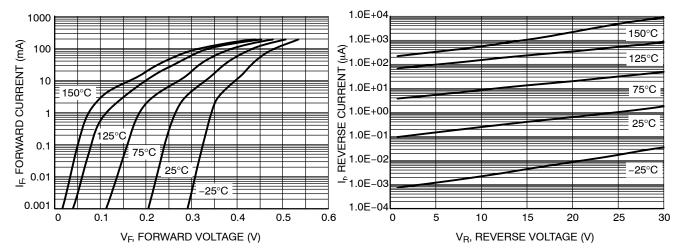


Figure 1. Forward Voltage

Figure 2. Leakage Current

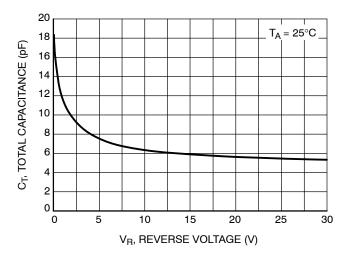


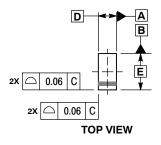
Figure 3. Total Capacitance

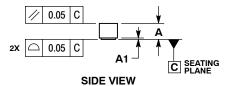
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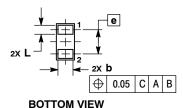
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PACKAGE DIMENSIONS

DSN2, **0.6x0.3**, **0.4P**, **(0201)**CASE 152AA-01
ISSUE O





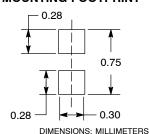


NOTES:

- DIMENSIONING AND TOLERANCING PER
 ASME Y14.5M. 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.24	0.30		
A1	0.00	0.01		
b	0.22	0.28		
D	0.30	BSC		
Е	BSC			
е	0.40 BSC			
L	0.12	0.18		

MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

See Application Note AND8398/D for more mounting details
*For additional information on our Pb-Free strategy and soldering
details, please download the ON Semiconductor Soldering and
Mounting Techniques Reference Manual, SOLDERRM/D.

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